NSN 5961-01-171-6431



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-171-6431 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** 0.335 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204aa **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 collector to base voltage/static/emitter open and 250.0 collector to emitter voltage, dc with specified circuit between base and emitter and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case

No

Shelf Life:

Unit Of Measure:

Demilitarization:

N/a

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